NSN 5961-01-065-0823

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View Online at https://aerobasegroup.com/nsn/5961-01-065-0823 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 325.0 breakdown voltage, collector-to-base, emitter open and 300.0 breakdown voltage, collector-to-emitter, base open and 10.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 70.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface (may be tin coated) gold **Precious Material:** Gold **Test Data Document:** 95105-352-8516 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:**

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N/a

1 case and 2 pin Shelf Life:

Unit Of Measure:

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No

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